

Vishay Siliconix

Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.0562			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.0745			
I _D (A) per leg	15			
Configuration	Dual			
Package	PowerPAK SO-8L			

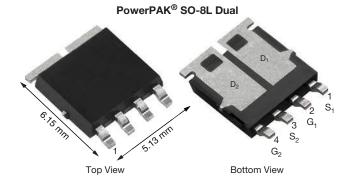
FEATURES

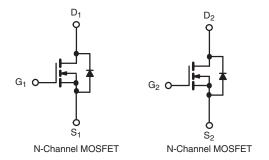
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





ABSOLUTE MAXIMUM RATINGS	$T_C = 25$ °C, unless	s otherwise noted	i)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	60		
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current a	T _C = 25 °C	1	15		
Continuous Drain Current 4	T _C = 125 °C	I _D	10.5		
Continuous Source Current (Diode conduction	on) ^a	I _S	8	Α	
Pulsed Drain Current ^b		I _{DM}	60		
Single Pulse Avalanche Current		I _{AS}	16		
ingle Pulse Avalanche Energy		E _{AS}	12	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	34	W	
	T _C = 125 °C	P_{D}	11	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	
Soldering Recommendations (Peak temperature) d, e		-	260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient PC	CB mount c	R _{thJA}	85	°C/W
Junction-to-Case (Drain)		R_{thJC}	4.3	C/VV

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static						L	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 60 V, T _J = 125 °C	-	-	50	
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	20	-	-	Α
Drain-Source On-State Resistance a		V _{GS} = 10 V	I _D = 3.7 A	-	0.0470	0.0562	Ω
		V _{GS} = 10 V	I _D = 3.7 A, T _J = 125 °C	-	-	0.0989	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 3.7 A, T _J = 175 °C	-	-	0.1254	
		V _{GS} = 4.5 V	I _D = 3.3 A	-	0.0620	0.0745	
Forward Transconductance b	g _{fs}	V _{DS} = 15 V, I _D = 5 A		-	11	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			=	357	446	
Output Capacitance	Coss	V _{GS} = 0 V V _{DS} = 30 V, f = 1 MHz		-	66	83	pF
Reverse Transfer Capacitance	C _{rss}			=.	26	33	1
Total Gate Charge ^c	Qg			=.	8.1	12	nC
Gate-Source Charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_D = 4.5 \text{ A}$	-	1.3	-	
Gate-Drain Charge ^c	Q _{gd}			-	1.7	-	
Gate Resistance	R_g	f = 1 MHz		1.1	-	7	Ω
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V}, \text{ R}_L = 30 \Omega$ $I_D \cong 1 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		-	6	9	- ns
Rise Time ^c	t _r			-	6	9	
Turn-Off Delay Time ^c	t _{d(off)}			=.	12	18	
Fall Time ^c	t _f]		-	7	11	
Source-Drain Diode Ratings and Chara	icteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	60	Α
Forward Voltage	V _{SD}	I _F =	2.4 A, V _{GS} = 0 V	-	0.8	1.1	V

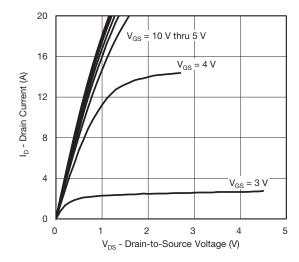
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

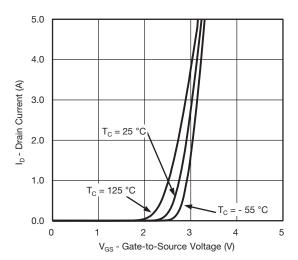
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



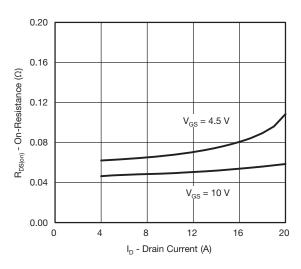
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



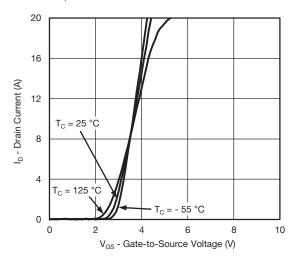
Output Characteristics



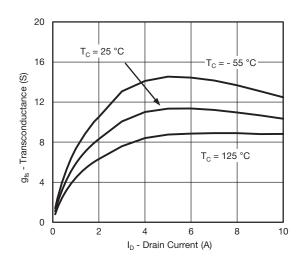
Transfer Characteristics



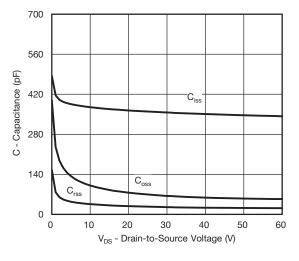
On-Resistance vs. Drain Current



Transfer Characteristics

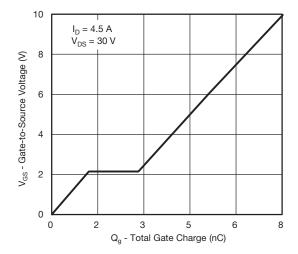


Transconductance

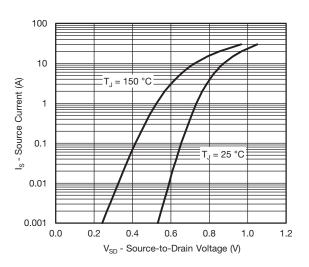




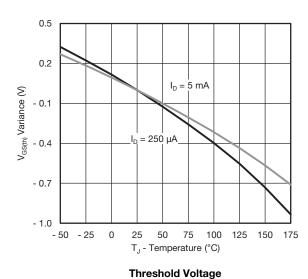
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

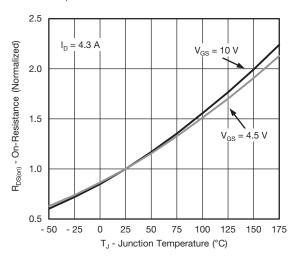


Gate Charge

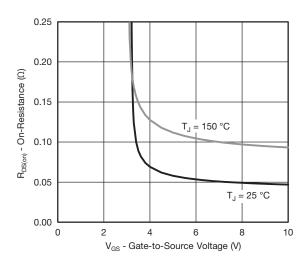


Source Drain Diode Forward Voltage

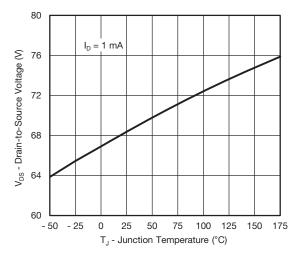




On-Resistance vs. Junction Temperature



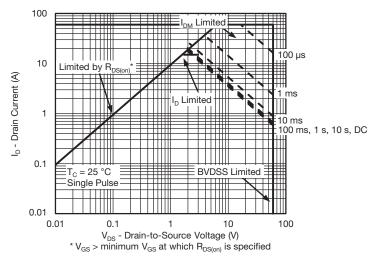
On-Resistance vs. Gate-to-Source Voltage



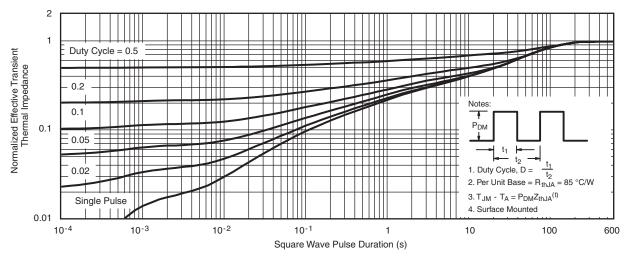
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



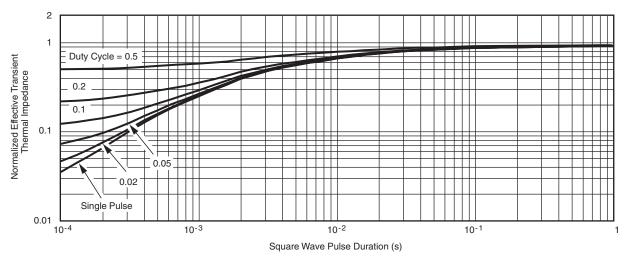
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg263267.





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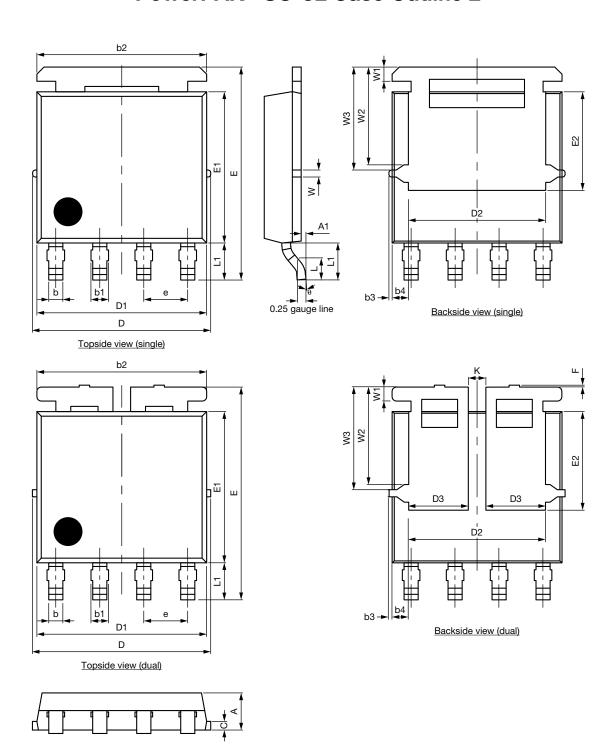
REVISION	REVISION HISTORY a				
REVISION	DATE	DESCRIPTION OF CHANGE			
В	04-Aug-15	Revised R _g minimum limit			
С	14-Jun-16	Corrected I _D in product summary table			

Note

a. As of April 2014



PowerPAK® SO-8L Case Outline 2





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DIM.	MILLIMETERS				INCHES	
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	1.00	1.07	1.14	0.039	0.042	0.045
A1	0.00	-	0.127	0.00	-	0.005
b	0.33	0.41	0.48	0.013	0.016	0.019
b1	0.44	0.51	0.58	0.017	0.020	0.023
b2	4.80	4.90	5.00	0.189	0.193	0.197
b3		0.094			0.004	
b4		0.47			0.019	
С	0.20	0.25	0.30	0.008	0.010	0.012
D	5.00	5.13	5.25	0.197	0.202	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.86	3.96	4.06	0.152	0.156	0.160
D3	1.63	1.73	1.83	0.064	0.068	0.072
е		1.27 BSC		0.050 BSC		
Е	6.05	6.05 6.15 6.25		0.238	0.242	0.246
E1	4.27	4.37	4.47	0.168	0.172	0.176
E2	2.75	2.85	2.95	0.108	0.112	0.116
F	-	-	0.15	-	-	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K		0.51			0.020	
W	0.23			0.009		
W1	0.41			0.016		
W2	2.82			0.111		
W3	2.96			0.117		
θ	0°	-	10°	0°	-	10°

ECN: C21-1498-Rev. C, 01-Nov-2021

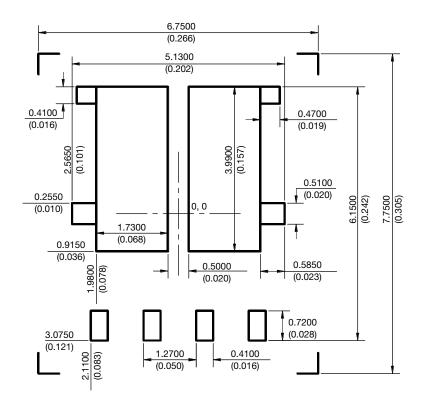
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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